### TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT MULTI CHIP

# TD62M3702F

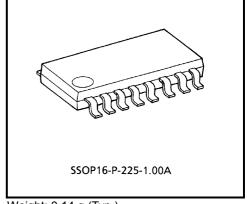
### LOW SATURATION VOLTAGE DRIVER FOR MOTOR

 $\ensuremath{\text{TD62M3702F}}$  is Multi Chip IC incorporates 6 low saturation discrete transistors.

This IC is suitable for a battery use motor drive applications.

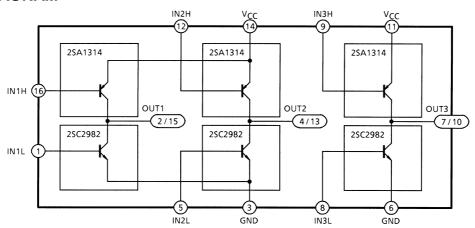
### **FEATURES**

- Suitable for High Efficiency Motor drive circuit
- External Input Resistor
- SSOP16 (1 mm pitch) small package sealed
- Low Saturation Voltage
  - : VCE (sat) = 0.20 V (Typ.) at IO = 1 A VCE (sat) = 0.40 V (Typ.) at IO = 2 A (Upper and Lower side total)

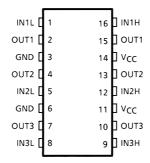


Weight: 0.14 g (Typ.)

### **BLOCK DIAGRAM**



### **PIN CONNECTION (TOP VIEW)**



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## MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage	V <sub>CC</sub>	15	V	
	V <sub>CBO</sub>	15	V	
Breakdown Voltage	V <sub>CEO</sub>	15		
	V <sub>BEO</sub>	6		
Output Current	I <sub>O (AVE)</sub>	2	А	
Output Current	IO (PEAK)	4 (Note 1)		
Base Current	Ι <sub>Β</sub>	0.4	Α	
Power Dissipation	PD	700 (Note 2)	mW	
Junction Temperature	Tj	150	°C	
Operating Temperature	T <sub>opr</sub>	-40~85	°C	
Storage Temperature	T <sub>stg</sub>	-55~150	°C	

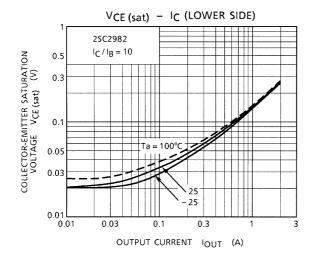
Note 1: T = 10 ms single pulse

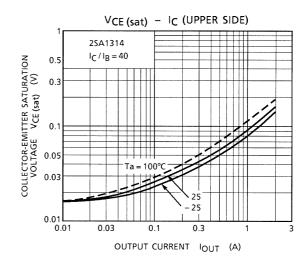
Note 2: Free Air

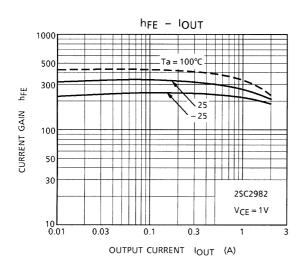
### **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

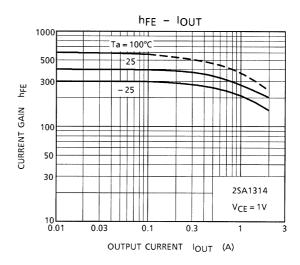
CHARACTERISTIC	SYMBOL		TEST CIR- CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Current Gain	h <sub>FE (1)</sub>		_	$V_{CE} = 0.4 \text{ V}, I_{C} = 30 \text{ mA}$	160	_	600	_	
	h <sub>FE (2)</sub>		_	V <sub>CE</sub> = 0.4 V, I <sub>C</sub> = 0.2 A	160	_	600		
Current Gain Ratio	h <sub>FE (1)</sub> / h <sub>FE (2)</sub>		_	V <sub>CE</sub> = 0.4 V, I <sub>C</sub> = 30 mA / V <sub>CE</sub> = 0.4 V, I <sub>C</sub> = 0.2 A	0.75	_	1.25		
Saturation Voltage	V <sub>CE (sat)</sub>		_	$I_C = -1 \text{ A}, I_B = -25 \text{ mA}$	_	-0.1	-0.25	· V	
	(Upper side)	I <sub>C</sub> = -2 A, I <sub>B</sub> = -50 mA		_	-0.2	-0.50			
	VCE (sat) (Lower side)		_	I <sub>C</sub> = 1 A, I <sub>B</sub> = 25 mA	_	0.1	0.30		
				I <sub>C</sub> = 2 A, I <sub>B</sub> = 50 mA	_	0.2	0.50		
	V <sub>CE</sub> (sat) (Summing Total)		_	I <sub>C</sub> = 1 A, I <sub>B</sub> = 25 mA	_	0.2	0.55		
				I <sub>C</sub> = 2 A, I <sub>B</sub> = 50 mA	_	0.4	1.0		
Transition Frequency	f <sub>T</sub>		_	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.5 A	_	140	_	MHz	
Leakage Current	I <sub>OL</sub> (Upper side) (Lower side)	(Upper side)		V <sub>CC</sub> = -15 V	_	0	-10		
		1 -	V <sub>CC</sub> = 15 V	_	0	10	μΑ		
Base-Emitter Forward Voltage	V <sub>BE</sub> (PNP)		_	V <sub>CE</sub> = -1 V, I <sub>C</sub> = -2 A	_	-0.84	-1.5	V	
	V <sub>BE</sub> (NPN)		_	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 2 A	_	0.84	1.5	v	

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### PRECAUTIONS for USING

This IC does not integrate protection circuits such as overcurrent and overvoltage protectors.

Thus, if excess current or voltage is applied to the IC, the IC may be damaged. Please design the IC so that excess current or voltage will not be applied to the IC.

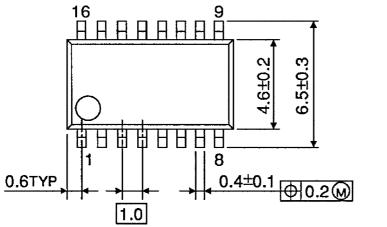
Utmost care is necessary in the design of the output line, VCC and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

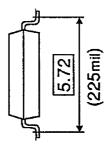
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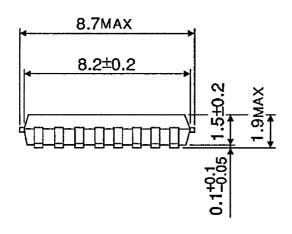
### **PACKAGE DIMENSIONS**

SSOP16-P-225-1.00A

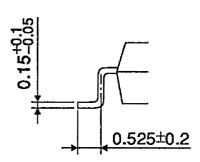
Unit: mm







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Weight: 0.14 g (Typ.)

#### **RESTRICTIONS ON PRODUCT USE**

000707EBA

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